

Dual Input, High Speed, Dual Channel Power MOSFET Driver

#### **Features**

- Logic AND/NAND input
- 3V and 5V Input compatible
- Clocking speeds up to 10 MHz
- 20 ns Switching/delay time
- 2A Peak drive
- Isolated drains
- Low output impedance
- Low quiescent current
- Wide operating voltage— 4.5V-16V

#### **Applications**

- Short circuit protected switching
- Under-voltage shut-down circuits
- Switch-mode power supplies
- Motor controls
- Power MOSFET switching
- Switching capacitive loads
- Shoot-thru protection
- Latching drivers

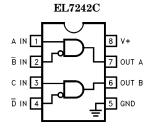
### **Ordering Information**

Part No.	Temp. Rang	ge Pkg.	Outline #
EL7242CN	-40°C to +85	5°C 8-Pin P-DI	P MDP0031
EL7242CS	-40°C to +85	5°C 8-Pin SOIC	MDP0027
EL7252CN	-40°C to +85	5°C 8-Pin P-DI	P MDP0031
EL7252CS	-40°C to +85	5°C 8-Pin SOIC	MDP0027

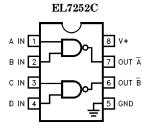
#### **General Description**

The EL7242C/EL7252C dual input, 2-channel drivers achieve the same excellent switching performance of the EL7212 family while providing added flexibility. The 2-input logic and configuration is applicable to numerous power MOSFET drive circuits. As with other Elantec drivers, the EL7242C/EL7252C are excellent for driving large capacitive loads with minimal delay and switching times. "Shoot-thru" protection and latching circuits can be implemented by simply "cross-coupling" the 2channels.

### **Connection Diagrams**



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Manufactured under U.S. Patent Nos. 5,334,883, #5,341,047

# TD is 3.1in

### EL7242C/EL7252C

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#### **Absolute Maximum Ratings**

Supply (V+ to Gnd) 16.5V Operating Junction Temperature 125°C

Input Pins -0.3V to +0.3V above  $V^+$  Power Dissipation

Combined Peak Output Current 4A SOIC 570 mW

Storage Temperature Range  $-65^{\circ}$ C to  $+150^{\circ}$ C  $+150^{\circ}$ C PDIP 1050 mW Ambient Operating Temperature  $-40^{\circ}$ C to  $+85^{\circ}$ C

#### Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore  $T_J = T_C = T_A$ .

Test Level Test Procedure

 $\begin{tabular}{ll} I&100\%&production tested and QA sample tested per QA test plan QCX0002.\\ II&100\%&production tested at $T_A=25^\circ$C and QA sample tested at $T_A=25^\circ$C$,} \end{tabular}$ 

 $T_{
m MAX}$  and  $T_{
m MIN}$  per QA test plan QCX0002.

III QA sample tested per QA test plan QCX0002.
 IV Parameter is guaranteed (but not tested) by Design and Characterization Data.

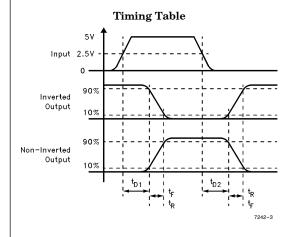
V Parameter is typical value at  $T_A = 25^{\circ}\text{C}$  for information purposes only.

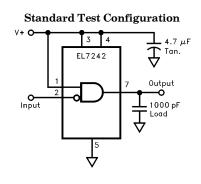
#### DC Electrical Characteristics T<sub>A</sub> = 25°C, V = 15V unless otherwise specified

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Parameter	Description	Test Conditions	Min	Тур	Max	Test Level	Units
Input							
$V_{IH}$	Logic "1" Input Voltage		2.4			I	v
$I_{IH}$	Logic "1" Input Current	@V+		0.1	10	I	μΑ
$v_{\rm IL}$	Logic "0" Input Voltage				0.8	I	v
I <sub>IL</sub>	Logic "0" Input Current	@0V		0.1	10	I	μΑ
V <sub>HVS</sub>	Input Hysteresis			0.3		v	v
Output			•	•			
R <sub>OH</sub>	Pull-Up Resistance	$I_{OUT} = -100 \text{ mA}$		3	6	I	Ω
R <sub>OL</sub>	Pull-Down Resistance	$I_{OUT} = +100 \text{ mA}$		4	6	I	Ω
$I_{ m PK}$	Peak Output Current	Source Sink		2 2		IV	A
I <sub>DC</sub>	Continuous Output Current	Source/Sink	100			I	mA
Power Supply		•	•				
I <sub>S</sub>	Power Supply Current	Inputs High		1	2.5	I	mA
$V_S$	Operating Voltage		4.5		16	I	v

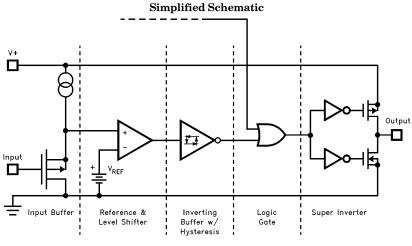
### Dual Input, High Speed, Dual Channel Power MOSFET Driver

AC Electrical Characteristics T <sub>A</sub> = 25°C, V = 15V unless otherwise specified							
Parameter	Description	Test Conditions	Min	Тур	Max	Test Level	Units
Switching Chara	acteristics						
	Rise Time	$egin{aligned} C_{ m L} &= 500 \  m pF \ C_{ m L} &= 1000 \  m pF \end{aligned}$			10 20	IV	ns
$t_F$	Fall Time	$C_{L} = 500 \text{ pF}$ $C_{L} = 1000 \text{ pF}$			10 20	IV	ns
t <sub>D-ON</sub>	Turn-On Delay Time			20	25	IV	ns
t <sub>D-OFF</sub>	Turn-Off Delay Time			20	25	IV	ns



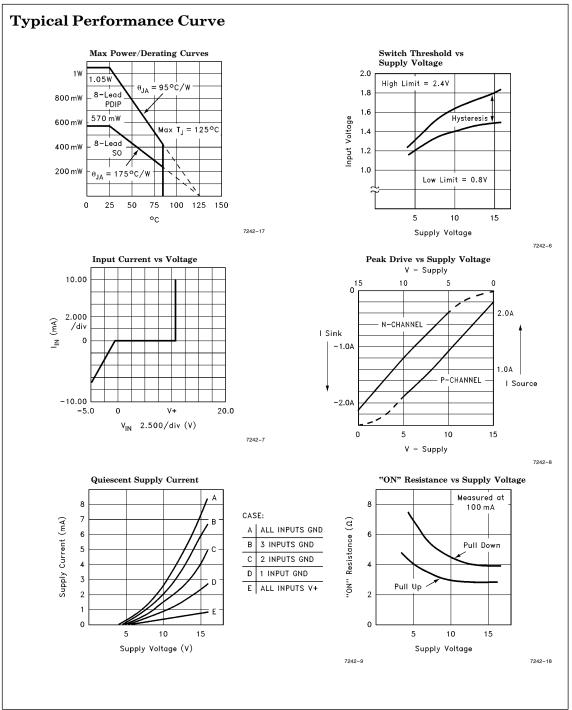


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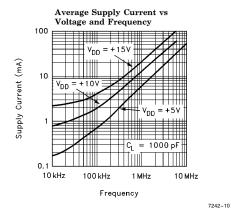
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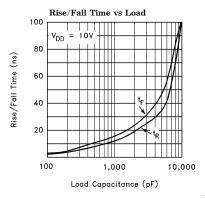
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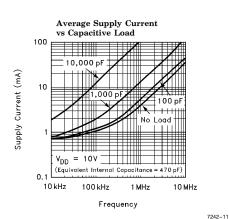


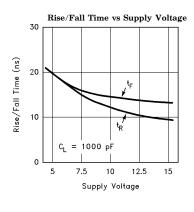
### Dual Input, High Speed, Dual Channel Power MOSFET Driver

### Typical Performance Curve — Contd.





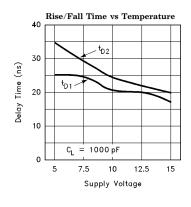


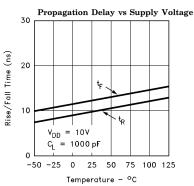


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### Dual Input, High Speed, Dual Channel Power MOSFET Driver

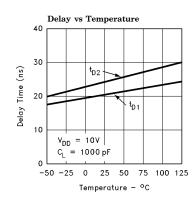
### ${\bf Typical\ Performance\ Curve-Contd.}$





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Dual Input, High Speed, Dual Channel Power MOSFET Driver

#### General Disclaimer

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